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# FDB86563\_F085

# N-Channel PowerTrench<sup>®</sup> MOSFET 60 V, 110 A, 1.8 m $\Omega$

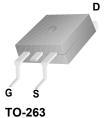
#### **Features**

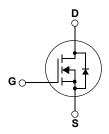
- Typical  $R_{DS(on)}$  = 1.6 mΩ at  $V_{GS}$  = 10V,  $I_D$  = 80 A
- Typical  $Q_{q(tot)}$  = 126 nC at  $V_{GS}$  = 10V,  $I_D$  = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

# **Applications**

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems







December 2014

FDB SERIES

For current package drawing, please refer to the Fairchild website at https://www.fairchildsemi.com/package-drawings/TO/TO263A02.pdf

#### **MOSFET Maximum Ratings** T<sub>J</sub> = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
$V_{DSS}$	Drain-to-Source Voltage		60	V
$V_{GS}$	Gate-to-Source Voltage		±20	V
	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> = 25°C	110	Δ.
ID	Pulsed Drain Current $T_C = 25^{\circ}C$		See Figure 4	Α
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	614	mJ
D	Power Dissipation		333	W
$P_D$	Derate Above 25°C		2.22	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.45	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W

#### Notes

- 1: Current is limited by bondwire configuration.
- 2: Starting T<sub>J</sub> = 25°C, L = 0.3mH, I<sub>AS</sub> = 64A, V<sub>DD</sub> = 60V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche.

  3: R<sub>0,JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder
- 3: R<sub>θ,JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θ,JC</sub> is guaranteed by design, while R<sub>θ,JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

## **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86563	FDB86563_F085	D2-PAK(TO-263)	330mm	24mm	800units

Units

Max.

# **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted.

**Parameter** 

Off Ch	Off Characteristics							
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	$I_D = 250 \mu A$ ,	V <sub>GS</sub> = 0V	60	-	-	V	
	Drain-to-Source Leakage Current	V <sub>DS</sub> =60V,	$T_J = 25^{\circ}C$	-	-	1	μΑ	
IDSS	Dialii-to-Source Leakage Current	$V_{GS} = 0V$	$T_J = 175^{\circ}C \text{ (Note 4)}$	-	-	1	mA	
$I_{GSS}$	Gate-to-Source Leakage Current	V <sub>GS</sub> = ±20V		-	-	±100	nA	

**Test Conditions** 

Min.

Тур.

## **On Characteristics**

Symbol

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.0	2.9	4.0	V
Drain to Source On Begintance	I <sub>D</sub> = 80A,	$T_{J} = 25^{\circ}C$	-	1.6	1.8	mΩ	
NDS(on)	R <sub>DS(on)</sub> Drain to Source On Resistance	V <sub>GS</sub> = 10V	$T_J = 175^{\circ}C \text{ (Note 4)}$	-	2.8	3.2	mΩ

# **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	.,	-V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, -f = 1MHz		10100	-	pF
C <sub>oss</sub>	Output Capacitance				2355	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1101112			186	-	pF
$R_g$	Gate Resistance	f = 1MHz		-	4.5	-	Ω
$Q_{g(ToT)}$	Total Gate Charge	$V_{GS} = 0$ to 10V	V <sub>DD</sub> = 48V	-	126	163	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	I <sub>D</sub> = 80A	-	19	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge		_	-	48	-	nC
$Q_{qd}$	Gate-to-Drain "Miller" Charge			-	18	-	nC

# **Switching Characteristics**

t <sub>on</sub>	Turn-On Time		-	-	213	ns
t <sub>d(on)</sub>	Turn-On Delay		-	28	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 30V, I <sub>D</sub> = 80A,	-	110	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	$V_{DD} = 30V, I_{D} = 80A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$	-	79	-	ns
t <sub>f</sub>	Fall Time		-	60	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	250	ns

## **Drain-Source Diode Characteristics**

V	Source-to-Drain Diode Voltage	I <sub>SD</sub> =80A, V <sub>GS</sub> = 0V -	-	-	1.25	V
$V_{SD}$	Source-to-Drain blode voltage	$I_{SD}$ = 40A, $V_{GS}$ = 0V	-	-	1.2	٧
t <sub>rr</sub>	Reverse-Recovery Time	$I_F = 80A$ , $dI_{SD}/dt = 100A/\mu s$	-	98	129	ns
Q <sub>rr</sub>	Reverse-Recovery Charge	V <sub>DD</sub> = 48V	-	150	230	nC

#### Note

4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.

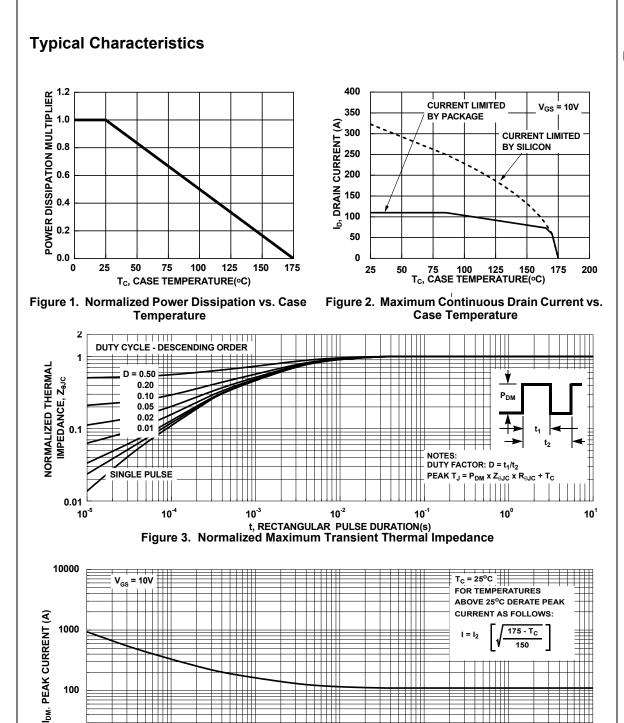


Figure 4. Peak Current Capability

10<sup>-2</sup>

t, RECTANGULAR PULSE DURATION(s)

10<sup>-1</sup>

10°

10<sup>1</sup>

10<sup>-3</sup>

SINGLE PULSE

10<sup>-4</sup>

10

10<sup>-5</sup>

# **Typical Characteristics**

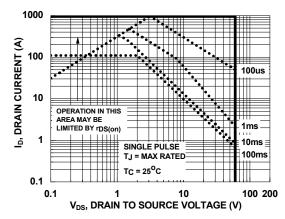
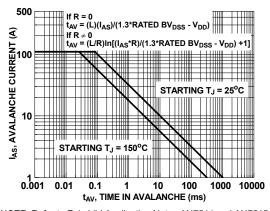


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching

Capability

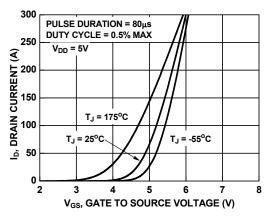


Figure 7. Transfer Characteristics

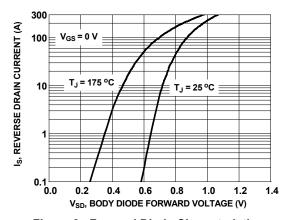


Figure 8. Forward Diode Characteristics

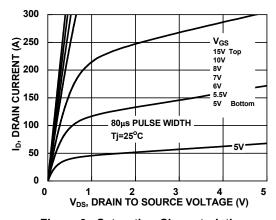


Figure 9. Saturation Characteristics

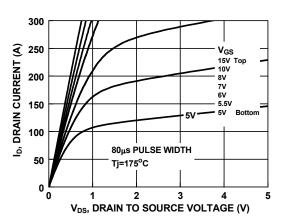


Figure 10. Saturation Characteristics

# **Typical Characteristics**

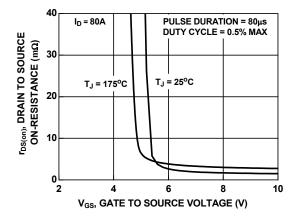


Figure 11. R<sub>DSON</sub> vs. Gate Voltage

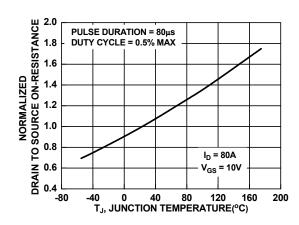


Figure 12. Normalized R<sub>DSON</sub> vs. Junction Temperature

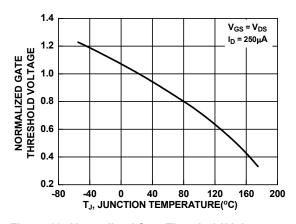


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

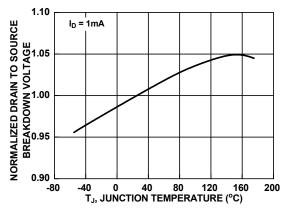


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

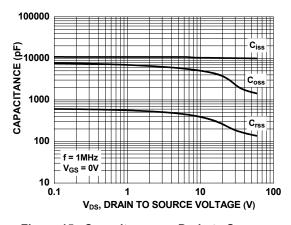


Figure 15. Capacitance vs. Drain to Source Voltage

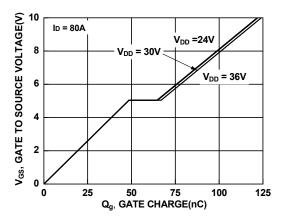


Figure 16. Gate Charge vs. Gate to Source Voltage





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